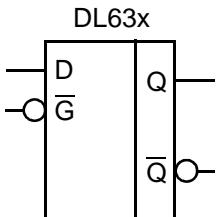


## AMI5HG 0.5 micron CMOS Gate Array

### Description

DL63x is a family of transparent, buffered D latches with active low gate transparency and without SET or RESET.

Logic Symbol	Truth Table																
	<table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th style="width: 40px;">D</th> <th style="width: 40px;">GN</th> <th style="width: 40px;">Q</th> <th style="width: 40px;">QN</th> </tr> </thead> <tbody> <tr> <td style="text-align: center;">L</td> <td style="text-align: center;">L</td> <td style="text-align: center;">L</td> <td style="text-align: center;">H</td> </tr> <tr> <td style="text-align: center;">H</td> <td style="text-align: center;">L</td> <td style="text-align: center;">H</td> <td style="text-align: center;">L</td> </tr> <tr> <td style="text-align: center;">X</td> <td style="text-align: center;">H</td> <td style="text-align: center;">NC</td> <td style="text-align: center;">NC</td> </tr> </tbody> </table> <p style="text-align: center;">NC = No Change</p>	D	GN	Q	QN	L	L	L	H	H	L	H	L	X	H	NC	NC
D	GN	Q	QN														
L	L	L	H														
H	L	H	L														
X	H	NC	NC														

### HDL Syntax

Verilog ..... DL63x *inst\_name* (Q, QN, D, GN);

VHDL..... *inst\_name*: DL63x port map (Q, QN, D, GN);

### Pin Loading

Pin Name	Equivalent Loads			
	DL631	DL632	DL634	DL636
D	1.1	1.0	1.0	1.0
GN	1.0	1.0	1.0	1.0

### Size And Power Characteristics

Cell	Equivalent Gates	Power Characteristics <sup>a</sup>	
		Static I <sub>DD</sub> (T <sub>J</sub> = 85°C) (nA)	EQL <sub>pd</sub> (Eq-load)
DL631	5.0	TBD	12.0
DL632	6.0	TBD	15.3
DL634	9.0	TBD	23.7
DL636	12.0	TBD	33.5

a. See page 2-15 for power equation.

## AMI5HG 0.5 micron CMOS Gate Array

### Propagation Delays (ns)

Conditions:  $T_J = 25^\circ\text{C}$ ,  $V_{DD} = 5.0\text{V}$ , Typical Process

Core Logic

Number of Equivalent Loads		1	4	8	13	17 (max)	
DL631	From: D To: Q	$t_{PLH}$ $t_{PHL}$	0.66 0.71	0.76 0.81	0.87 0.93	1.00 1.07	1.09 1.18
	From: D To: QN	$t_{PLH}$ $t_{PHL}$	0.61 0.58	0.71 0.70	0.83 0.83	0.96 0.98	1.06 1.09
	From: GN To: Q	$t_{PLH}$ $t_{PHL}$	0.77 0.90	0.87 1.00	0.98 1.12	1.11 1.26	1.21 1.37
	From: GN To: QN	$t_{PLH}$ $t_{PHL}$	0.78 0.68	0.88 0.79	1.00 0.92	1.13 1.08	1.24 1.20
	Number of Equivalent Loads		1	8	15	22	30 (max)
DL632	From: D To: Q	$t_{PLH}$ $t_{PHL}$	0.76 0.80	0.86 0.92	0.95 1.03	1.05 1.13	1.16 1.23
	From: D To: QN	$t_{PLH}$ $t_{PHL}$	0.62 0.58	0.74 0.74	0.84 0.86	0.95 0.97	1.06 1.08
	From: GN To: Q	$t_{PLH}$ $t_{PHL}$	0.87 0.99	0.97 1.11	1.06 1.21	1.14 1.30	1.24 1.40
	From: GN To: QN	$t_{PLH}$ $t_{PHL}$	0.80 0.70	0.91 0.86	1.01 0.96	1.10 1.06	1.21 1.17
	Number of Equivalent Loads		1	14	28	42	56 (max)
DL634	From: D To: Q	$t_{PLH}$ $t_{PHL}$	0.82 0.93	0.93 1.01	1.02 1.12	1.11 1.23	1.18 1.36
	From: D To: QN	$t_{PLH}$ $t_{PHL}$	0.67 0.58	0.74 0.73	0.83 0.84	0.94 0.94	1.05 1.03
	From: GN To: Q	$t_{PLH}$ $t_{PHL}$	0.96 1.12	1.01 1.24	1.10 1.34	1.20 1.43	1.31 1.51
	From: GN To: QN	$t_{PLH}$ $t_{PHL}$	0.85 0.69	0.90 0.79	0.99 0.91	1.10 1.04	1.22 1.17
	Number of Equivalent Loads		1	14	28	42	56 (max)

**AMI5HG 0.5 micron CMOS Gate Array**

	Number of Equivalent Loads		1	21	42	62	83 (max)
DL636	From: D	$t_{PLH}$	0.87	0.94	1.02	1.11	1.22
	To: Q	$t_{PHL}$	0.97	1.07	1.18	1.29	1.40
	From: D	$t_{PLH}$	0.74	0.86	0.94	1.01	1.08
	To: QN	$t_{PHL}$	0.65	0.74	0.85	0.96	1.08
	From: GN	$t_{PLH}$	0.99	1.07	1.15	1.23	1.34
	To: Q	$t_{PHL}$	1.18	1.31	1.39	1.47	1.56
	From: GN	$t_{PLH}$	0.93	1.04	1.12	1.19	1.26
	To: QN	$t_{PHL}$	0.77	0.90	1.01	1.09	1.17

Delay will vary with input conditions. See page 2-Reference for interconnect estimates.

**Timing Constraints**

Conditions:  $T_J = 25^\circ\text{C}$ ,  $V_{DD} = 5.0\text{V}$ , Typical Process

From	To	Parameter	Cell			
			DL631	DL632	DL634	DL636
Min GN Width	Low	$t_w$	0.66	0.69	0.73	0.83
Min D Setup		$t_{su}$	0.47	0.50	0.54	0.64
Min D Hold		$t_h$	0.14	0.14	0.14	0.14

**Logic Schematic**
